Product data sheet

1. Product profile

1.1. General description

General-purpose Zener diodes in an SOD123F small and flat lead Surface-Mounted Device (SMD) plastic package.

1.2. Features and benefits

- Total power dissipation: ≤ 830 mW
- Wide working voltage range: nominal 2.4 V to 75 V (E24 range)
- · Small plastic package suitable for surface-mounted design
- · AEC-Q101 qualified

1.3. Applications

· General regulation functions

1.4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{F}	forward voltage	I _F = 10 mA	[1]	-	-	0.9	V
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[2]	-	-	375	mW
			[3]	-	-	830	mW

- [1] Pulse test: $t_p \le 300 \ \mu s; \ \delta \le 0.02.$
- [2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².

2. Pinning information

Table 2. Pinning

Pin	Description		Simplified outline	Graphic symbol
1	cathode	[1]	1 2	K [4] A
2	anode			006aaa152

[1] The marking bar indicates the cathode.



Voltage regulator diodes

3. Ordering information

Table 3. Ordering information

Type number	Package							
	Name	Description	Version					
BZT52H-B2V4 to BZT52H-C75 [1]	-	plastic surface-mounted package; 2 leads	SOD123F					

^[1] The series consists of 74 types with nominal working voltages from 2.4 V to 75 V.

4. Marking

Table 4. Marking codes

Type number	Marking code						
BZT52H-B2V4	DC	BZT52H-B15	DX	BZT52H-C2V4	В3	BZT52H-C15	BN
BZT52H-B2V7	DD	BZT52H-B16	DY	BZT52H-C2V7	B4	BZT52H-C16	BP
BZT52H-B3V0	DE	BZT52H-B18	DZ	BZT52H-C3V0	B5	BZT52H-C18	BQ
BZT52H-B3V3	DF	BZT52H-B20	E1	BZT52H-C3V3	B6	BZT52H-C20	BR
BZT52H-B3V6	DG	BZT52H-B22	E2	BZT52H-C3V6	B7	BZT52H-C22	BS
BZT52H-B3V9	DH	BZT52H-B24	E3	BZT52H-C3V9	B8	BZT52H-C24	ВТ
BZT52H-B4V3	DJ	BZT52H-B27	E4	BZT52H-C4V3	В9	BZT52H-C27	BU
BZT52H-B4V7	DK	BZT52H-B30	E5	BZT52H-C4V7	BA	BZT52H-C30	BV
BZT52H-B5V1	DL	BZT52H-B33	E6	BZT52H-C5V1	BB	BZT52H-C33	BW
BZT52H-B5V6	DM	BZT52H-B36	E7	BZT52H-C5V6	ВС	BZT52H-C36	BX
BZT52H-B6V2	DN	BZT52H-B39	E8	BZT52H-C6V2	BD	BZT52H-C39	BY
BZT52H-B6V8	DP	BZT52H-B43	E9	BZT52H-C6V8	BE	BZT52H-C43	BZ
BZT52H-B7V5	DQ	BZT52H-B47	EA	BZT52H-C7V5	BF	BZT52H-C47	C1
BZT52H-B8V2	DR	BZT52H-B51	EB	BZT52H-C8V2	BG	BZT52H-C51	C2
BZT52H-B9V1	DS	BZT52H-B56	EC	BZT52H-C9V1	ВН	BZT52H-C56	C3
BZT52H-B10	DT	BZT52H-B62	ED	BZT52H-C10	BJ	BZT52H-C62	C4
BZT52H-B11	DU	BZT52H-B68	EE	BZT52H-C11	BK	BZT52H-C68	C5
BZT52H-B12	DV	BZT52H-B75	EF	BZT52H-C12	BL	BZT52H-C75	C6
BZT52H-B13	DW	-	-	BZT52H-C13	BM	-	-

Voltage regulator diodes

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
l _F	forward current			-	250	mA
I _{ZSM}	non-repetitive peak reverse current			-	see Table 8,9 and 10	
P _{ZSM}	non-repetitive peak reverse power dissipation		[1]	-	40	W
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[2]	-	375	mW
			[3]	-	830	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	+150	°C
T _{stg}	storage temperature			-65	+150	°C

6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from	in free air		-	-	330	K/W
	junction to ambient			-	-	150	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point		[3]	-	-	70	K/W

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

 ^[1] t_p = 100 μs; square wave; T_j = 25 °C prior to surge.
 [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².

Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².

Soldering point of cathode tab.

Voltage regulator diodes

7. Characteristics

Table 7. Characteristics

 T_i = 25 °C unless otherwise specified.

Symbol	Parameter Conditions			Min	Тур	Max	Unit
V_{F}	forward voltage	I _F = 10 mA	[1]	-	-	0.9	V

^[1] Pulse test: $t_p \le 300 \ \mu s; \ \delta \le 0.02.$

Table 8. Characteristics per type; BZT52H-B2V4 to BZT52H-C24

 T_j = 25 °C unless otherwise specified.

BZT52H Sel -xxx		Working voltage V _Z (V); I _Z = 5 mA		Maximum resistance	differential r _{dif} (Ω)		Reverse current I _R (μA)		erature icient V/K); mA	Diode capacitance C _d (pF) [1]	Non-repetitive peak reverse current I _{ZSM} (A) [2]
		Min	Max	I _Z = 1 mA	I _Z = 5 mA	Max	V _R (V)	Min	Max	Max	Max
2V4	В	2.35	2.45	400	85	50	1	-3.5	0.0	450	6.0
	С	2.2	2.6								
2V7	В	2.65	2.75	500	83	20	1	-3.5	0.0	450	6.0
	С	2.5	2.9								
3V0	В	2.94	3.06	500	95	10	1	-3.5	0.0	450	6.0
	С	2.8	3.2								
3V3	В	3.23	3.37	500	95	5	1	-3.5	0.0	450	6.0
	С	3.1	3.5								
3V6	B 3.53 3.67 500	500	95	5	1	-3.5	0.0	0 450	6.0		
	С	3.4	3.8								
3V9	9 B 3.82 3.98 500	500	95	3	1	-3.5	0.0	450	6.0		
	С	3.7	4.1								
	В	4.21	4.39	500	95	3	1	-3.5	0.0	450	6.0
	С	4.0	4.6								
4V7	В	4.61	4.79	500	78	3	2	-3.5	0.2	300	6.0
	С	4.4	5.0								
5V1	В	5.0	5.2	480	60	2	2	-2.7	1.2	300	6.0
	С	4.8	5.4								
5V6	В	5.49	5.71	400	40	1	2	-2.0	2.5	300	6.0
	С	5.2	6.0								
6V2	В	6.08	6.32	150	10	3	4	0.4	3.7	200	6.0
	С	5.8	6.6								
6V8	В	6.66	6.94	80	8	2	4	1.2	4.5	200	6.0
	С	6.4	7.2								
7V5	В	7.35	7.65	80	10	1	5	2.5	5.3	150	4.0
	С	7.0	7.9								
8V2	B 8.04 8.36 80	80	10	0.7	5	3.2	6.2	150	4.0		
	С	7.7	8.7								
9V1	В	8.92	9.28	100 10	10 0	0.5	6	3.8	7.0	150	3.0
	С	8.5	9.6				0.0		3.0 7.0		

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BZT52H -xxx	Sel	Working voltage V _Z (V); I _Z = 5 mA		Maximum differential resistance $r_{dif}\left(\Omega\right)$			Reverse current I _R (μA)		erature cient V/K); mA	Diode capacitance C _d (pF) [1]	Non-repetitive peak reverse current I _{ZSM} (A) [2]
		Min	Max	I _Z = 1 mA	I _Z = 5 mA	Max	V _R (V)	Min	Max	Max	Max
10	В	9.8	10.2	70	10	0.2	7	4.5	8.0	90	3.0
	С	9.4	10.6								
11	В	10.8	11.2		10	0.1	8	5.4	9.0	85	2.5
	С	10.4	11.6								
12	В	11.8	12.2	90	10	0.1	8	6.0	3.0 10.0	85	2.5
	С	11.4	12.7								
13	B 12.7 13.3 110 C 12.4 14.1	110	10	0.1	8	7.0	11.0	80	2.5		
15	В	14.7	15.3	110	15	0.05	10.5	9.2	13.0	75	2.0
	С	13.8	15.6								
16	В	15.7	16.3	170	20	0.05	11.2	10.4	14.0	75	1.5
	С	15.3	17.1								
18	В	17.6	18.4	170	20	0.05	12.6	12.4	16.0	70	1.5
	С	16.8	19.1								
20	В	19.6	20.4	220	20	0.05	14	14.4	18.0	60	1.5
	С	18.8	21.2								
22	В	21.6	22.4	220	25	0.05	15.4	16.4	20.0	60	1.25
	С	20.8	23.3								
24	В	23.5	24.5	220 3	30	0.05 16.8	16.8	18.4	18.4 22.0	55	1.25
	С	22.8	25.6								

Table 9. Characteristics per type; BZT52H-B27 to BZT52H-C51

 T_i = 25 °C unless otherwise specified.

BZT52H -xxx	Sel	Working voltage V _Z (V); I _Z = 2 mA		Maximum differential resistance $r_{dif}\left(\Omega\right)$			Κ. ,		erature cient //K); mA	Diode capacitance C _d (pF) [1]	Non-repetitive peak reverse current I _{ZSM} (A) [2]		
		Min	Max	I _Z = 1 mA	I _Z = 5 mA	Max	V _R (V)	Min	Max	Max	Max		
27	В	26.5	27.5	250	40	0.05	18.9	21.4	25.3	50	1.0		
	С	25.1	28.9										
30	В	29.4	30.6	250	250	250 40	40	0.05	0.05 21	24.4	29.4	50	1.0
(С	28.0	32.0										
33	В	32.3	33.7	250 40	40	0.05	23.1	27.4	33.4	45	0.9		
	С	31.0	35.0										
36	В	35.3	36.7	250	60	0.05	25.2	30.4	37.4	45	0.8		
	С	34.0	38.0										
39	В	38.2	39.8	300	75	0.05	27.3	33.4	41.2	45	0.7		
	С	37.0	41.0		. 0								
43	В	42.1	43.9	325 8	80	0.05	30.1	37.6	46.6	40	0.6		
(С	40.0	46.0										

^[1] $f = 1 \text{ MHz}; V_R = 0 \text{ V}.$ [2] $t_p = 100 \text{ } \mu\text{s}; T_{amb} = 25 \text{ }^{\circ}\text{C}.$

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BZT52H -xxx	Sel			Maximum differential resistance $r_{dif}(\Omega)$		Reverse current I _R (μA)		Temperature coefficient S_Z (mV/K); $I_Z = 5$ mA		Diode capacitance C _d (pF) [1]	Non-repetitive peak reverse current I _{ZSM} (A) [2]
		Min	Max	I _Z = 1 mA	I _Z = 5 mA	Max	V _R (V)	Min	Max	Max	Max
47	В	46.1	47.9	325	90	0.05)5 32.9	42.0	51.8	40	0.5
	С	44.0	50.0								
51	В	50.0 52.0 350 1	100	0.05	35.7	46.6	57.2	57.2 40	0.4		
	С	48.0	54.0	-							

- [1] $f = 1 \text{ MHz}; V_R = 0 \text{ V}.$ [2] $t_p = 100 \text{ } \mu\text{s}; T_{amb} = 25 \text{ }^{\circ}\text{C}.$

Table 10. Characteristics per type; BZT52H-B56 to BZT52H-C75

 T_i = 25 °C unless otherwise specified.

BZT52H -xxx	Sel	Working voltage V _Z (V); I _Z = 2 mA		Maximum differential resistance $r_{dif}(\Omega)$					erature cient V/K); mA	Diode capacitance C _d (pF) [1]	Non-repetitive peak reverse current I _{ZSM} (A) [2]
		Min	Max	I _Z = 0.5 mA	I _Z = 2 mA	Max	V _R (V)	Min	Max	Max	Max
56	В	54.9	57.1	375	120	0.05	39.2	52.2	63.8	40	0.3
	С	52.0	60.0								
62	В	60.8	63.2	400	0 140	0.05	05 43.4	58.8	71.6	35	0.3
	С	58.0	66.0								
68	В	66.6	69.4	400	160	0.05	47.6	65.6	79.8	35	0.25
	С	64.0	72.0								
75 E	В	73.5	76.5	400	175	0.05	52.5	73.4	73.4 88.6	35	0.20
	С	70.0	79.0								

- [1] f = 1 MHz; $V_R = 0 \text{ V}$.
- [2] $t_p = 100 \,\mu s$; $T_{amb} = 25 \,^{\circ}C$.

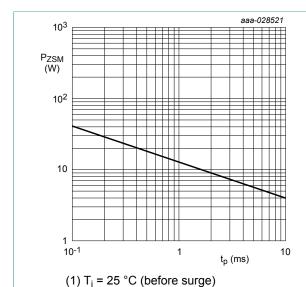


Fig. 1. Non-repetitive peak reverse power dissipation as a function of pulse duration; maximum values

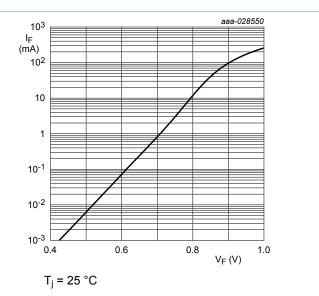


Fig. 2. Forward current as a function of forward voltage; typical values (BZT52H-B/C2V4)

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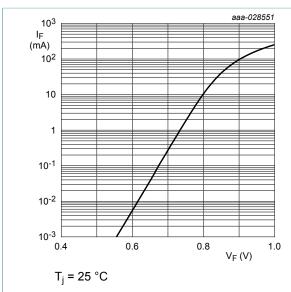


Fig. 3. Forward current as a function of forward voltage; typical values (BZT52H-B/C6V8)

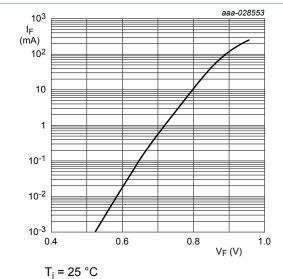


Fig. 5. Forward current as a function of forward voltage; typical values (BZT52H-B/C75)

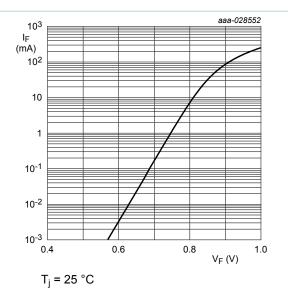


Fig. 4. Forward current as a function of forward voltage; typical values (BZT52H-B/C7V5)

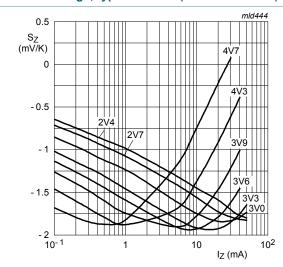


Fig. 6. Temperature coefficient as a function of working current; typical values (BZT52H-B/C2V4 to B/C4V7)

 T_i = 25 °C to 150 °C

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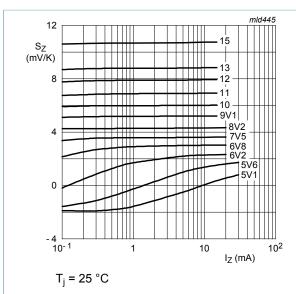


Fig. 7. Temperature coefficient as a function of working current; typical values (BZT52H-B/C5V1 to B/C15)

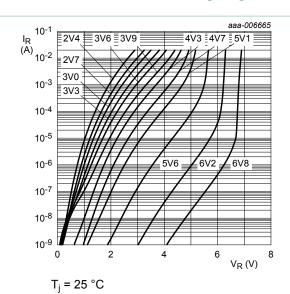


Fig. 8. Reverse current as a function of reverse voltage; typical values (BZT52H-B/C2V4 to BZT52H-B/C6V8)

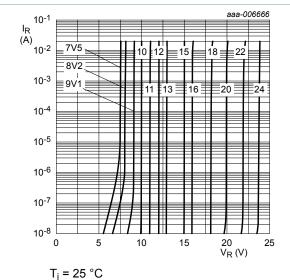


Fig. 9. Reverse current as a function of reverse voltage; typical values (BZT52H-B/C7V5 to BZT52H-B/C24)

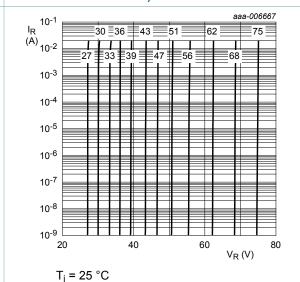


Fig. 10. Reverse current as a function of reverse voltage; typical values (BZT52H-B/C27 to BZT52H-B/C75)

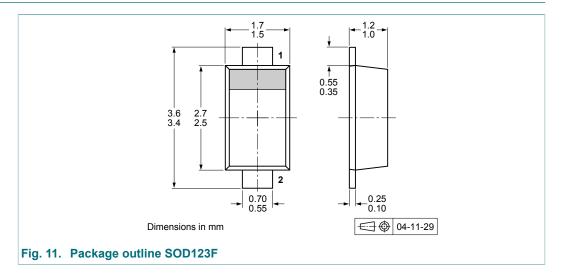
8. Test information

8.1. Quality information

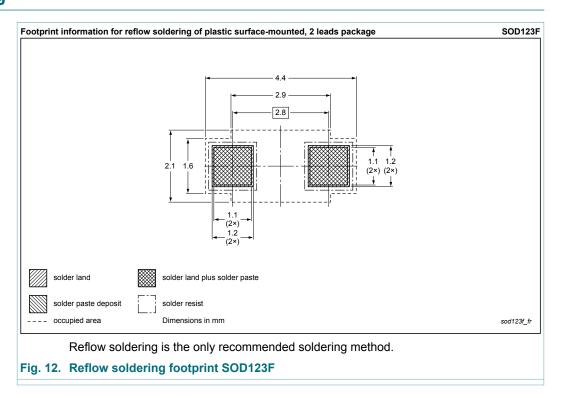
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

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9. Package outline



10. Soldering



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11. Revision history

Table 11. Revision history

Table 11. Nevision instory						
Document ID	Release date	Data sheet status	Change notice	Supersedes		
BZT52H_SER v.4	20190121	Product data sheet	-	BZT52H_SER v.3		
Modifications:	Nexperia. • Legal texts h	f this data sheet has been re ave been adapted to the ne cs: figures updated		vith the identity guidelines of ere appropriate.		
BZT52H_SER v.3	20091115	Product data sheet	-	BZT52H_SER v.2		
BZT52H_SER v.2	20091115	Product data sheet	-	BZT52H_SER v.1		
BZT52H_SER v.1	20051222	Product data sheet	-	-		

Voltage regulator diodes

12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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Voltage regulator diodes

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